NSN 5961-00-137-0966



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-00-137-0966 **Inclosure Material:** Plastic **Overall Length:** Between 0.175 inches and 0.205 inches **Terminal Length:** 0.500 inches **Overall Height:** Between 0.170 inches and 0.210 inches **Overall Width:** Between 0.125 inches and 0.165 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Internal Junction Configuration:** Npn **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, gate-to-source, with all other terminals short-circuited to source and 60.0 breakdown voltage, collector-to-base, emitter open **Current Rating Per Characteristic:** 50.00 nanoamperes collector cutoff current, dc, with specified circuit between base and emitter **Power Rating Per Characteristic:** 350.0 milliwatts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

Fiig:

No

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Demilitarization: